

# N-HFA08TB120 (7)

### **Nell High Power Products**

# FRED Ultrafast Soft Recovery Diode, 8 A

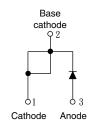


### **FEATURES**

- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for industrial level

#### **BENEFITS**

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count



TO-220AC

#### **DESCRIPTION**

HFA08TB120 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200V and 8 A continuous current, the HFA08TB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the FRED product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The FRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These FRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The FRED HFA08TB120 is ideally suited for applications in power supplies and conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

PRODUCT SUMMARY				
$V_R$	1200 V			
V <sub>F</sub> at 8A at 25 °C	3.3 V			
I <sub>F(AV)</sub>	8 A			
t <sub>rr</sub> (typical)	30 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub> (typical)	140 nC			
dl <sub>(rec)M</sub> /dt (typical) at 125 °C	85 A/μS			
I <sub>RRM</sub> (typical)	4.5 A			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V <sub>R</sub>		1200	V		
Maximum continuous forward current	I <sub>F</sub>	Tc = 100 °C	8			
Single pulse forward current	I <sub>FSM</sub>		130	Α		
Maximum repetitive forward current	I <sub>FRM</sub>		32			
Maximum power discipation	P <sub>D</sub>	Tc = 25 °C	73	W		
Maximum power dissipation		Tc = 100 °C	29	VV		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C		



# N-HFA08TB120 1018

# Nell High Power Products

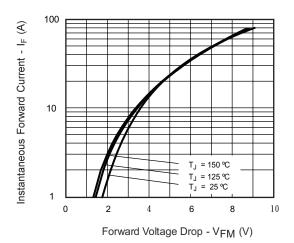
ELECTRICAL SPECIFICATIONS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	1200	-	-	
Maximum forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 8.0 A	-	2.5	3.3	V
		I <sub>F</sub> = 16 A	-	3.0	4.1	
		I <sub>F</sub> = 8.0 A, T <sub>J</sub> = 125 °C	-	2.3	3.1	
Maximum reverse	I <sub>RM</sub>	$V_R = V_R$ rated	-	0.31	10	
leakage current		$T_J = 125$ °C, $V_R = V_R$ rated	-	135	1000	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200V	-	11	20	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS PERLEG (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5A$ , $I_R = 1.0A$ , $I_{RR}$	= 1.0A, I <sub>RR</sub> = 250mA (RG#1 CKT)		28	35	- ns
		$I_F = 1.0 \text{ A}, dI_F/dt = -200 \text{ A/µs}, V_R = 30 \text{ V}, T_J = 25^{\circ}\text{C}$		-	30	-	
	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8.0A dI <sub>F</sub> /dt = -200 A/μs V <sub>R</sub> = 200 V	-	63	95	- 115
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	105	160	
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	4.5	8	A
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	6.1	11	
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	140	380	nC
	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	335	880	
Peak rate of fall of	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	133	-	- A/μs
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	85	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1.7		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	1		
Weight			-	6	1	g	
			-	0.21	-	OZ.	
Mounting torque			6.0 (5.0)	=	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-220AC	HFA08TB120				



Fig.1 Maximum Forward Voltage Drop Characteristics



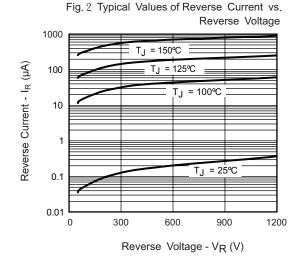


Fig.3 Typical Junction Capacitance vs. Reverse Voltage

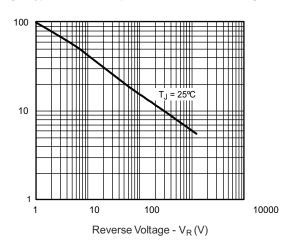
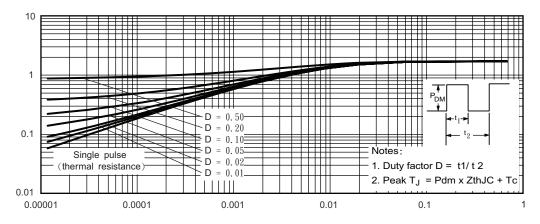


Fig.4 Maximum Thermal Impedance  $Z_{thJC}$  Characteristics



Rectangular Pulse Duration (sec)- t<sub>1</sub>



Fig. 5 Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

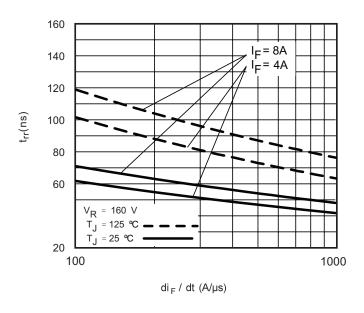


Fig.7 Typical Stored Charge vs. dl<sub>F</sub>/dt

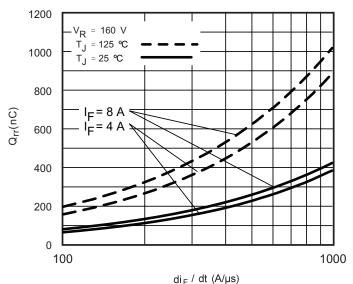


Fig.6 Typical Recovery Current vs. dip/dt

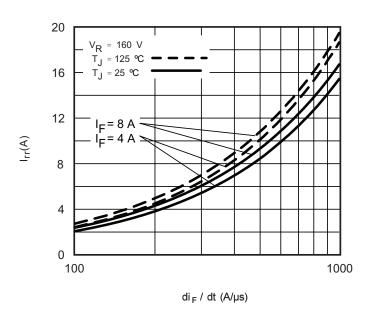


Fig.8 Typical dI<sub>(rec)M</sub>/dt vs. dI<sub>F</sub>/dt

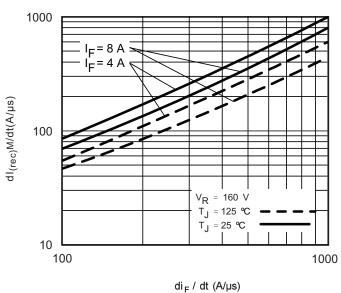




Fig.9 Reverse Recovery Parameter Test Circuit

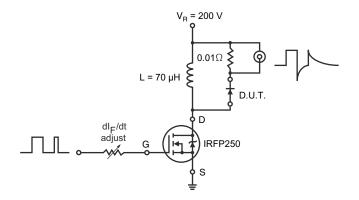
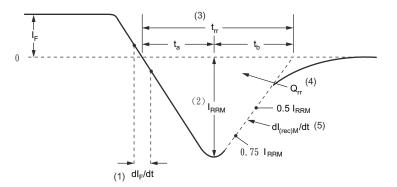


Fig.10 Reverse Recovery Waveform and Definitions



- (1) dI<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 



### **ORDERING INFORMATION TABLE**

Device code N - HFA 08 TB

1 - Nell Semiconductors product

(3)

(4)

120

(5)

2 - FRED family

3 - Current rating (08 = 8 A)

(2)

4 - Package : TB = TO-220AC

5 - Voltage rating (120 = 1200 V)

